SDAS236A - DECEMBER 1982 - REVISED JANUARY 1995

- Latchable P-Input Ports With Power-Up Clear
- Choice of Logical or Arithmetic (Two's Complement) Comparison
- Data and PLE Inputs Utilize pnp Input Transistors to Reduce dc Loading Effects
- Approximately 35% Improvement in ac Performance Over Schottky TTL While **Performing More Functions**
- Cascadable to n Bits While Maintaining **High Performance**
- 10% Less Power Than STTL for an 8-Bit Comparison
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (NT) and Ceramic (JT) 300-mil DIPs

description

These advanced Schottky devices are capable of performing high-speed arithmetic or logic comparisons on two 8-bit binary or two's complement words. Two fully decoded decisions about words P and Q are externally available at two outputs. These devices are fully expandable to any number of bits without external gates. To compare words of longer lengths, the P > QOUT and P < QOUT outputs of a stage handling less significant bits can be connected to the P > QIN and P < QIN inputs of the next stage handling more significant bits. The cascading paths are implemented with only a two-gate-level delay to reduce overall comparison times for long words. Two alternative methods of cascading are shown in application information.

The latch is transparent when P latch-enable (PLE) input is high; the P-input port is latched

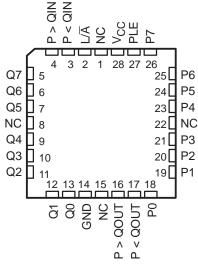
when PLE is low. This provides the designer with temporary storage for the P-data word. The enable circuitry is implemented with minimal delay times to enhance performance when cascaded for longer words. The PLE, P, and Q data inputs utilize pnp input transistors to reduce the low-level current input requirement to typically -0.25 mA, which minimizes dc loading effects.

The SN54AS885 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74AS885 is characterized for operation from 0°C to 70°C.



SN74AS885DW OR NT PACKAGE (TOP VIEW)									
L/A	1 U	24	V _{CC}						
P < QIN [2	23	PLE						
P > QIN [3	22	P7						
Q7 [4	21	P6						
Q6 [5	20	P5						
Q5 [6	19	P4						
Q4 [7	18	P3						
Q3 [8	17	P2						
Q2 [9	16	P1						
Q1 [10	15	P0						
Q0 [11	14	P < QOUT						
GND [12	13	P > QOUT						
SN54AS885 FK PACKAGE (TOP VIEW)									
NIC NIC									

SN54AS885 ... JT PACKAGE





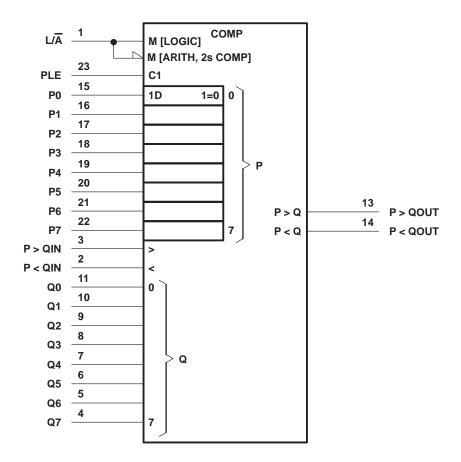
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FUNCTION TABLE										
		INF	PUTS		OUTPUTS					
COMPARISON	L/A	DATA P0–P7, Q0–Q7	P > QIN	P < QIN	P > QOUT	P < QOUT				
Logical	Н	P > Q	Х	Х	Н	L				
Logical	Н	P < Q	Х	Х	L	Н				
Logical [†]	н	P = Q	H or L	H or L	H or L	H or L				
Arithmetic	L	P AG Q	Х	Х	н	L				
Arithmetic	L	Q AG P	Х	Х	L	Н				
Arithmetic [†]	L	P = Q	H or L	H or L	H or L	H or L				

[†] In these cases, P > QOUT follows P > QIN and P < QOUT follows P < QIN.

AG = arithmetically greater than

logic symbol[‡]

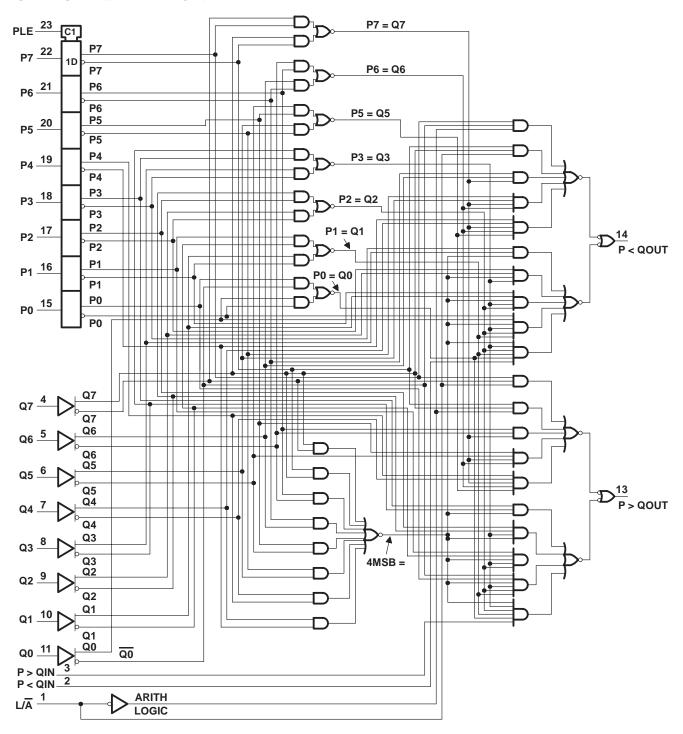


[‡] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the DW, JT, and NT packages.



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logic diagram (positive logic)



Pin numbers shown are for the DW, JT, and NT packages.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V _{CC}	
Operating free-air temperature range, T _A : SN54AS885	–55°C to 125°C
SN74AS885	0°C to 70°C
Storage temperature range	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		SN54AS885			SI	174AS88	5	UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.8			0.8	V
ЮН	High-level output current			-2			-2	mA
IOL	Low-level output current			20			20	mA
t _{su} *	Setup time, data before $PLE{\downarrow}$	2			2			ns
t _h *	Hold time, data after $PLE{\downarrow}$	4.5			4			ns
ТА	Operating free-air temperature	-55		125	0		70	°C

* On products compliant to MIL-STD-883, Class B, this parameter is based on characterization data but is not production tested.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CON	TEST CONDITIONS			85	SN	LINUT		
	PARAMETER	TESTCON	TEST CONDITIONS			MAX	MIN	TYP‡	MAX	UNIT
VIK		V _{CC} = 4.5 V,	lı = – 18 mA			-1.2			-1.2	V
VOH		V _{CC} = 4.5 V to 5.5 V,	$I_{OH} = -2 \text{ mA}$	V _{CC} -2	2		V _{CC} -2	2		V
VOL		V _{CC} = 4.5 V,	I _{OL} = 20 mA		0.35	0.5		0.35	0.5	V
Ι		V _{CC} = 5.5 V,	V _I = 7 V			0.1			0.1	mA
1	L/A		VI = 2.7 V			40			40	۸
ΙН	Others	$V_{CC} = 5.5 V,$	V = 2.7 V			20			20	μA
	L/A		V ₁ = 0.4 V			-4			-4	
ЧL	P > QIN, P < QIN	V _{CC} = 5.5 V,				-2			-2	mA
	P, Q, PLE	7				-1			-1	
۱ ₀ §		V _{CC} = 5.5 V,	V _O = 2.25 V	-20		-112	-20		-112	mA
ICC		V _{CC} = 5.5 V,	See Note 1		130	210		130	210	mA

[‡] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

\$ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, I_{OS}. NOTE 1: I_{CC} is measured with all inputs high except LA, which is low.



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PARAMETER	FROM TO (INPUT) (OUTPUT)			CL RL	c = 4.5 = 50 pF = 500 Ω = MIN t	; <u>)</u> ,	V,		UNIT	
	, , ,	, , , , , , , , , , , , , , , , , , ,	SI	N54AS88	85	SI	V74AS88	5		
			MIN	TYP†	MAX	MIN	TYP [†]	MAX		
^t PLH		P < QOUT, P > QOUT	2	8.5	14	1	8.5	13		
^t PHL	L/A		2	7.5	14	1	7.5	13	ns	
^t PLH	P < QIN,	P < QOUT,	2	5	10	1	5	8		
^t PHL	P > QIN	P > QOUT	2	5.5	10	1	5.5	8	ns	
^t PLH	Any P or Q	P < QOUT,	2	13.5	21	1	13.5	17.5		
^t PHL	data input	P > QOUT	2	10	17	1	10	15	ns	

switching characteristics (see Figure 3)

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

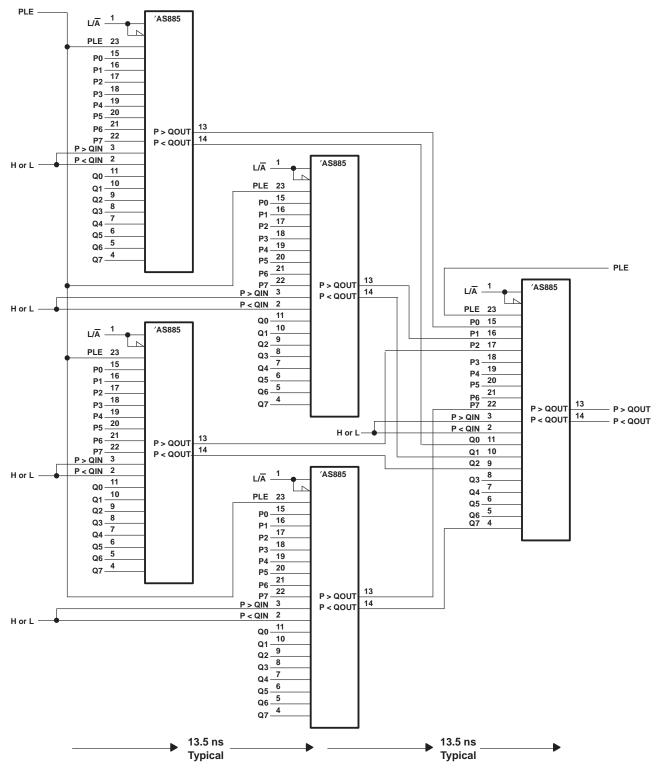
APPLICATION INFORMATION

The 'AS885 can be cascaded to compare words longer than eight bits. Figure 1 shows the comparison of two 32-bit words; however, the design is expandable to n bits. Figure 1 shows the optimum cascading arrangement for comparing words of 32 bits or greater. Typical delay times shown are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$ and use the standard advanced Schottky load of $R_L = 500 \Omega$, $C_L = 50 \text{ pF}$.

Figure 2 shows the fastest cascading arrangement for comparing 16-bit or 24-bit words. Typical delay times shown are at V_{CC} = 5 V, T_A = 25°C and use the standard advanced Schottky load of R_L = 500 Ω , C_L = 50 pF.



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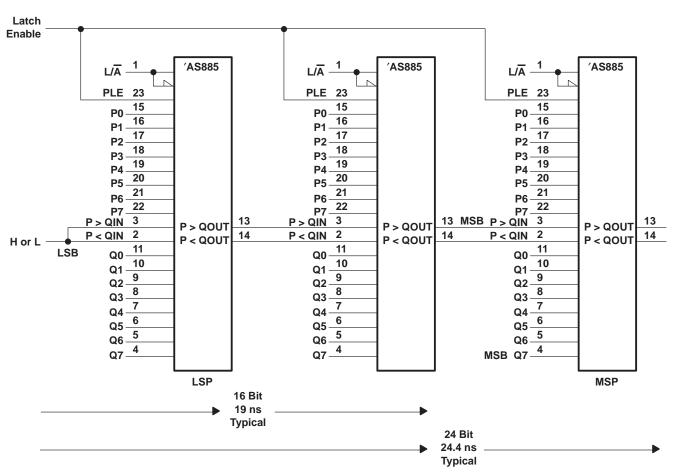


APPLICATION INFORMATION

Figure 1. 32-Bit to 72 (n)-Bit Magnitude Comparator



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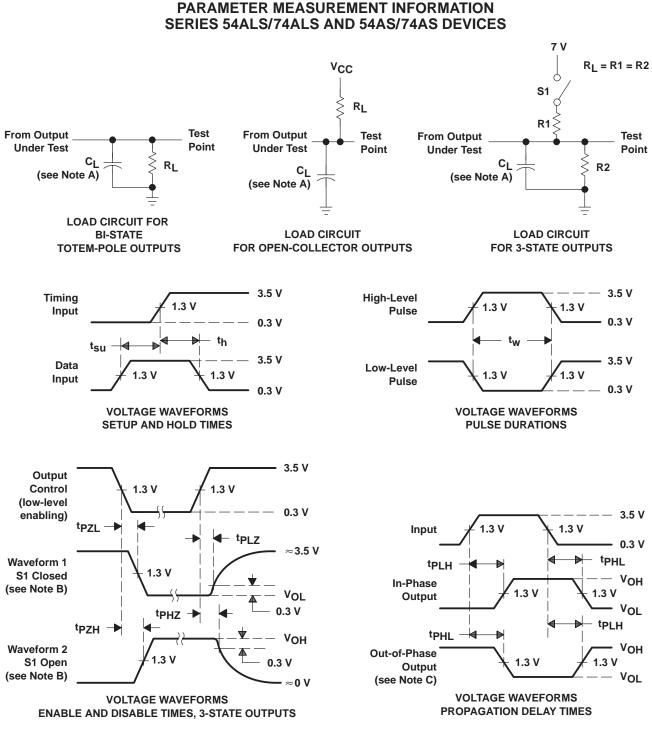


APPLICATION INFORMATION

Figure 2. Fastest Cascading Arrangement for Comparing 16-Bit or 24-Bit Words



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NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. When measuring propagation delay items of 3-state outputs, switch S1 is open.
- D. All input pulses have the following characteristics: PRR \leq 1 MHz, t_{f} = t_{f} = 2 ns, duty cycle = 50%.
- E. The outputs are measured one at a time with one transition per measurement.

Figure 3. Load Circuits and Voltage Waveforms





11-Jul-2015

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-89757013A	ACTIVE	LCCC	FK	28	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 89757013A SNJ54AS 885FK	Samples
5962-8975701KA	LIFEBUY	CFP	W	24	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8975701KA SNJ54AS885W	
5962-8975701LA	ACTIVE	CDIP	JT	24	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8975701LA SNJ54AS885JT	Samples
SN54AS885JT	ACTIVE	CDIP	JT	24	1	TBD	A42	N / A for Pkg Type	-55 to 125	SN54AS885JT	Samples
SN74AS885DW	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AS885	Samples
SN74AS885DWR	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	AS885	Samples
SN74AS885NT	LIFEBUY	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN74AS885NT	
SN74AS885NT3	OBSOLETE	PDIP	NT	24		TBD	Call TI	Call TI	0 to 70		
SN74AS885NTE4	LIFEBUY	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN74AS885NT	
SNJ54AS885FK	ACTIVE	LCCC	FK	28	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 89757013A SNJ54AS 885FK	Samples
SNJ54AS885JT	ACTIVE	CDIP	JT	24	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8975701LA SNJ54AS885JT	Samples
SNJ54AS885W	LIFEBUY	CFP	W	24	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8975701KA SNJ54AS885W	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.



PACKAGE OPTION ADDENDUM

11-Jul-2015

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54AS885, SN74AS885 :

Catalog: SN74AS885

• Military: SN54AS885

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

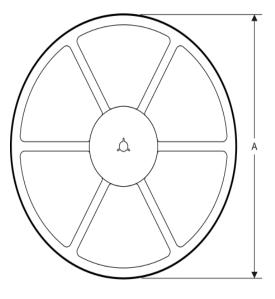
PACKAGE MATERIALS INFORMATION

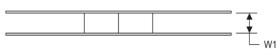
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TAPE AND REEL INFORMATION

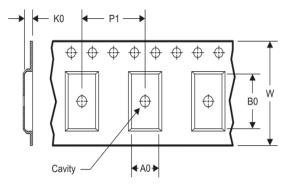
REEL DIMENSIONS

Texas Instruments





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

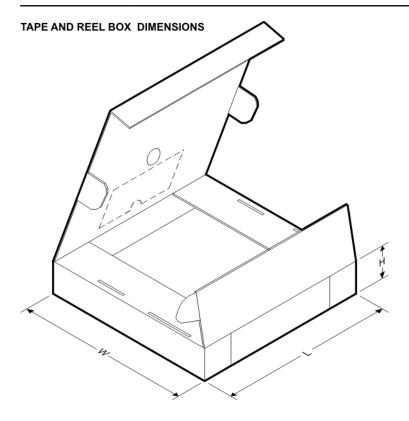
Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AS885DWR	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

14-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AS885DWR	SOIC	DW	24	2000	367.0	367.0	45.0

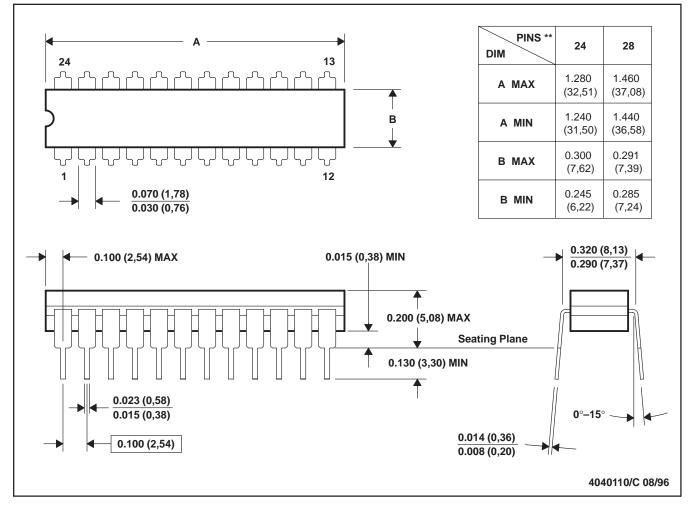
MECHANICAL DATA

MCER004A - JANUARY 1995 - REVISED JANUARY 1997

JT (R-GDIP-T**)

CERAMIC DUAL-IN-LINE

24 LEADS SHOWN



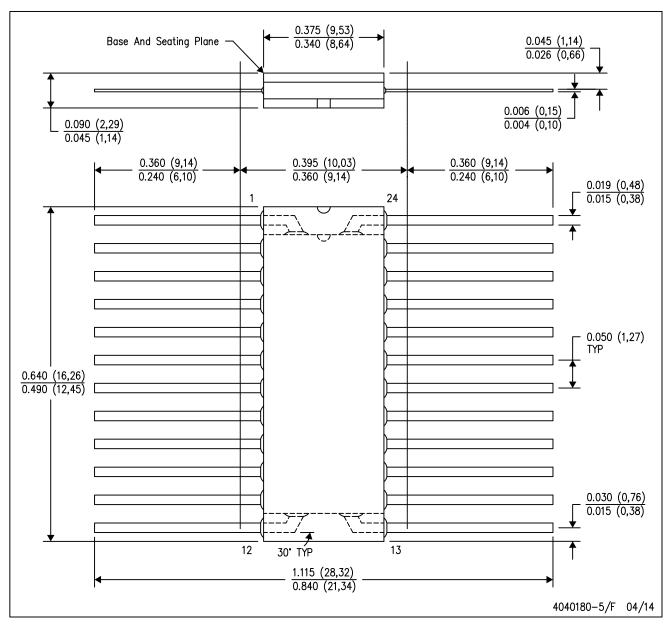
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP3-T24, GDIP4-T28, and JEDEC MO-058 AA, MO-058 AB



CERAMIC DUAL FLATPACK

W (R-GDFP-F24)



NOTES: A. All linear dimensions are in inches (millimeters).

- This drawing is subject to change without notice. В.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
 E. Falls within Mil-Std 1835 GDFP2-F20



LEADLESS CERAMIC CHIP CARRIER

FK (S-CQCC-N**) 28 TERMINAL SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

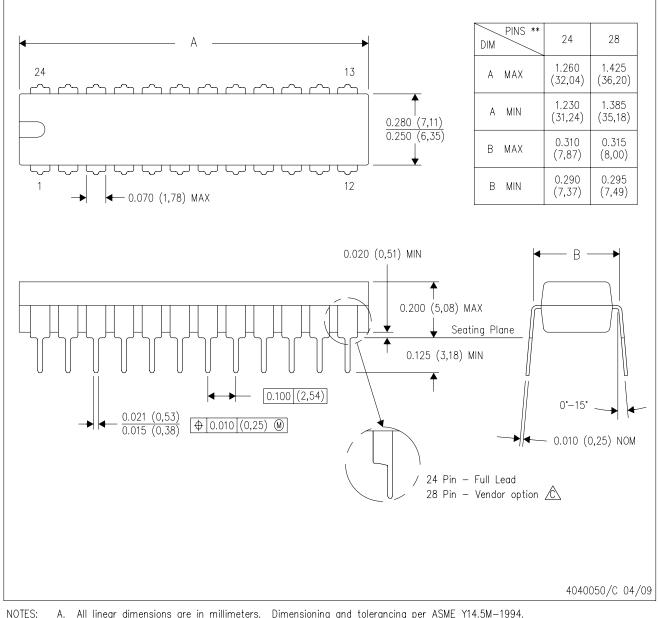
B. This drawing is subject to change without notice.

- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



NT (R-PDIP-T**) 24 pins shown

PLASTIC DUAL-IN-LINE PACKAGE



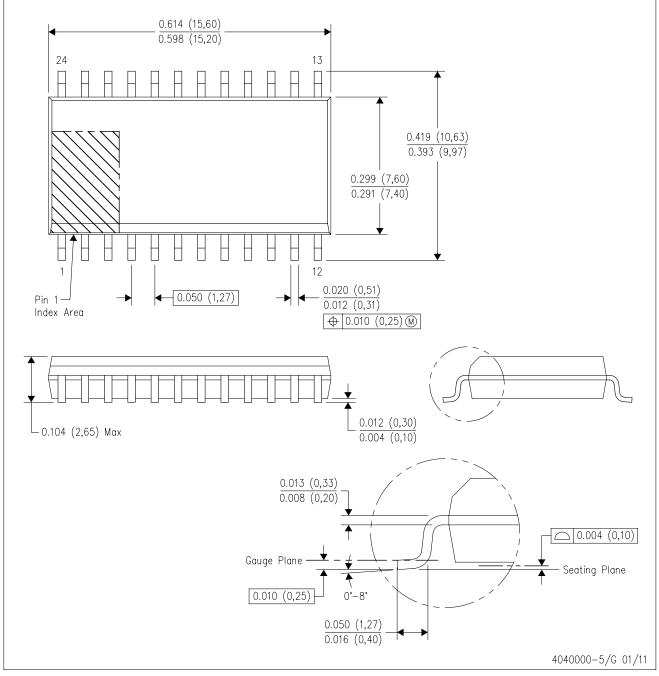
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 B. This drawing is subject to change without notice.

The 28 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AD.



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